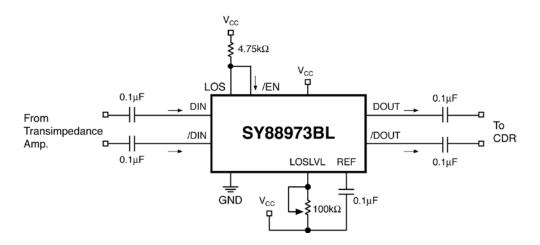
## **Typical Application Circuit**



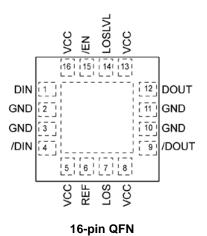
# Ordering Information<sup>(1)</sup>

Part Number	Package Type	Operating Range	Package Marking	Lead Finish	
SY88973BLMG <sup>(3)</sup>	QFN-16	Industrial	973B with Pb-Free bar-line indicator	Pb-Free Matte-Sn	
SY88973BLMGTR <sup>(2, 3)</sup>	QFN-16	Industrial	973B with Pb-Free bar-line indicator	Pb-Free Matte-Sn	

#### Notes:

- 1. Contact factory for die availability. Dice are guaranteed at TA = 25°C, DC Electricals only.
- 2. Tape and Reel.
- 3. Pb-Free package is recommended for new designs.

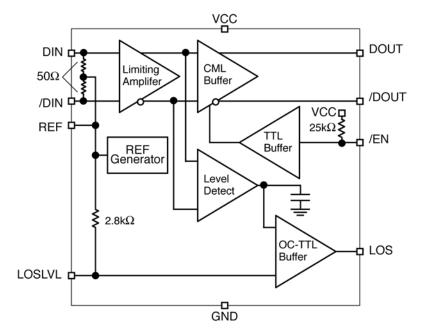
# **Pin Configuration**



# **Pin Description**

Pin Number (QFN)	Pin Name	Туре	Pin Function
15	/EN	TTL Input: Default is high.	Enable: De-asserts true data output when high. Incorporates 25k $\Omega$ pull-up to VCC.
1, 4	DIN, /DIN	Differential Data Input	Differential data input. Each pin internally terminates to REF through 50 $\Omega$ .
6	REF		Reference Voltage: Bypass with 0.01µF low ESR capacitor from REF to VCC to stabilize LOSLVL and REF.
14	LOSLVL	Input: Default is maximum sensitivity	Loss-of-Signal Level Set: A resistor from this pin to VCC sets the threshold for the data input amplitude at which the LOS output will be asserted.
2, 3, 10, 11 Exposed Pad	GND	Ground	Device ground. Exposed pad must be soldered (or equivalent) to the same potential as the ground pins.
7	LOS	Open Collector TTL Output	Loss-of-Signal: asserts high when the data input amplitude falls below the threshold set by LOSLVL. For proper operation, connect an external 4.75k $\Omega$ to 10k $\Omega$ pull-up resistor between this pin and Vcc.
9, 12	DOUT, /DOUT	Differential CML Output	Differential data output.
5, 8, 13, 16	VCC	Power Supply	Positive power supply. Bypass with $0.1\mu\text{F}  \ 0.01\mu\text{F}$ low ESR capacitors. $0.01\mu\text{F}$ capacitors should be as close as possible to VCC pins.

# **Functional Block Diagram**



## Absolute Maximum Ratings<sup>(1)</sup>

Supply Voltage (V <sub>CC</sub> )	0V to 4.0V
/EN, LOSLVL Voltage	0V to V <sub>CC</sub>
REF Current	±1mA
LOS Current	±5mA
DOUT, /DOUT Current	±25mA
DIN, /DIN Current	±10mA
Lead Temperature (soldering, 20sec.)	260°C
Storage Temperature (T <sub>s</sub> )	

## Operating Ratings<sup>(2)</sup>

Supply Voltage (V <sub>CC</sub> )	+3.0V to +3.6V
Ambient Temperature (T <sub>A</sub> )	40°C to +85°C
Junction Temperature (T <sub>J</sub> )	40°C to +120°C
Package Thermal Resistance	
QFN	
$\theta_{JA}$ (Still-Air)	61°C/W
Ψ <sub>JB</sub>	38°C/W

### **DC Electrical Characteristics**

 $V_{CC} = 3.0 \text{V}$  to 3.6V;  $T_A = -40 ^{\circ}\text{C}$  to +85°C, typical values at  $V_{CC} = 3.3 \text{V}$ ,  $T_A = 25 ^{\circ}\text{C}$ .

Symbol	Parameter	Condition	Min	Тур	Max	Units
I <sub>CC</sub>	Power Supply Current	Note 4 Note 5		28 45	42 62	mA mA
$V_{REF}$	REF Voltage			V <sub>CC</sub> -1.3		V
V <sub>LOSLVL</sub>	LOSLVL Voltage Range		$V_{REF}$		Vcc	V
V <sub>OH</sub>	Output HIGH Voltage	Note 6	V <sub>CC</sub> -0.020	V <sub>CC</sub> -0.005	Vcc	٧
V <sub>OL</sub>	Output LOW Voltage	Note 6	V <sub>CC</sub> -0.475	V <sub>CC</sub> -0.400	V <sub>CC</sub> -0.350	V
V <sub>OFFSET</sub>	Differential Output Offset	Note 6			±80	mV
Z <sub>O</sub>	Single-Ended Output Impedance		40	50	60	Ω
Zı	Single-Ended Input Impedance		40	50	60	Ω

### **TTL DC Electrical Characteristics**

 $V_{CC} = 3.0V$  to 3.6V;  $T_A = -40$ °C to +85°C.

Symbol	Parameter	Condition	Min	Тур	Max	Units
I <sub>OH</sub>	LOS Output Leakage	V <sub>OH</sub> = 3.6V			100	uA
V <sub>OL</sub>	LOS Output LOW Level	Sinking 2mA			0.5	V
V <sub>IH</sub>	/EN Input HIGH Voltage		2.0			V
V <sub>IL</sub>	/EN Input LOW Voltage				0.8	V
I <sub>IH</sub>	/EN Input HIGH Current	V <sub>IN</sub> = 2.7V			20	μA
		$V_{IN} = V_{CC}$			100	μΑ
I <sub>IL</sub>	/EN Input LOW Current	V <sub>IN</sub> = 0.5V	-300			uA

#### Notes:

- 1. Permanent device damage may occur if Absolute Maximum Ratings are exceeded. This is a stress rating only and functional operation is not implied at conditions other than those detailed in the operational sections of this data sheet. Exposure to Absolute Maximum Rating conditions for extended periods may affect device reliability.
- 2. The data sheet limits are not guaranteed if the device is operated beyond the operating ratings.
- 3. Thermal performance assumes the use of 4-layer PCB. Exposed pad must be soldered (or equivalent) to the device's most negative potential on the PCB.
- 4. Excludes current of CML output stage. See "Detailed Description."
- 5. Total device current with no output load.
- Output levels are based on a 50Ω to V<sub>CC</sub> load impedance. If the load impedance is different, the output level will be changed. Amplifier is in limiting mode.

## AC Electrical Characteristics<sup>(4)</sup>

 $V_{CC}=3.0V~to~3.6V;~T_{A}=-40^{\circ}C~to~+85^{\circ}C,~R_{LOAD}=50\Omega~to~V_{CC};~typical~values~at~V_{CC}=3.3V,~T_{A}=25^{\circ}C.$ 

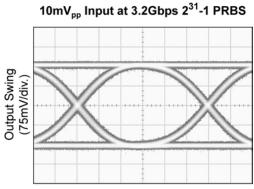
Symbol	Parameter	Condition	Min	Тур	Max	Units
PSRR	Power Supply Rejection Ratio			35		dB
t <sub>r</sub> , t <sub>f</sub>	Output Rise/Fall Times (20% to 80%)	Note 7		60	120	ps
t <sub>JITTER</sub>	Deterministic Random	Note 8		15 5		ps <sub>PP</sub> ps <sub>RMS</sub>
V <sub>ID</sub>	Differential Input Voltage Swing		10		1800	$mV_{PP}$
V <sub>OD</sub>	Differential Output Voltage Swing	Note 7	700	800	950	$mV_{PP}$
HYS	LOS Hysteresis	Note 9	2	4.6	8	dB
t <sub>OFF</sub>	LOS Release Time			0.1	0.5	μs
t <sub>ON</sub>	LOS Assert Time			0.2	0.5	μs
V <sub>SR</sub>	LOS Sensitivity Range	Note 10	10		35	$mV_{PP}$
B <sub>-3dB</sub>	-3dB Bandwidth			2.0		GHz
A <sub>V(Diff)</sub>	Differential Voltage Gain		32	38		dB
S <sub>21</sub>	Single-Ended Small-Signal Gain		26	32		dB

#### Notes:

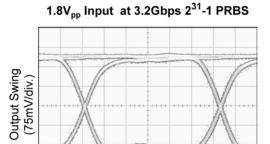
- 7. Amplifier in limiting mode. Input is a 200MHz square wave,  $t_r < 300ps$ .
- 8. Deterministic jitter measured using 2.488Gbps K28.5 pattern,  $V_{ID} = 10 \text{mV}_{PP}$ . Random jitter measured using 2.488Gbps K28.7 pattern,  $V_{ID} = 10 \text{mV}_{PP}$ .
- 9. Electrical signal.
- 10. This is the detectable range of input amplitudes that can assert LOS. The input amplitude to de-assert LOS is 2–8dB higher than the assert amplitude. See "Typical Operating Characteristics" for graphs showing how to choose a particular V<sub>LOSLVL</sub> or R<sub>LOSLVL</sub> for a particular LOS assert, and its associated de-assert amplitude. If increased LOS sensitivity and hysteresis are required, an application note entitled: "Notes on Sensitivity and Hysteresis in Micrel Post Amplifiers" is available at <a href="http://www.micrel.com/">http://www.micrel.com/</a> PDF/HBW/App-Notes/an-45.pdf.

### **Typical Operating Characteristics**

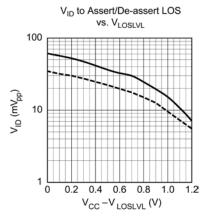
 $V_{CC}$  = 3.3V,  $T_{A}$  = 25°C,  $R_{LOAD}$  = 50  $\!\Omega$  to  $V_{CC},$  unless otherwise noted.

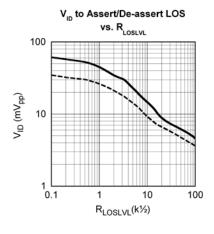


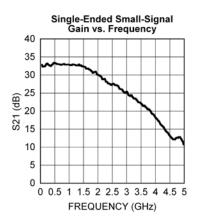


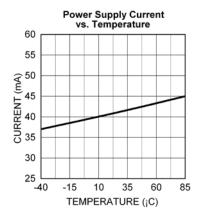


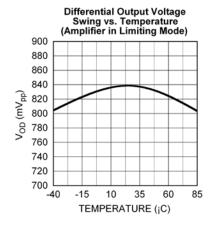
TIME (50ps/div.)

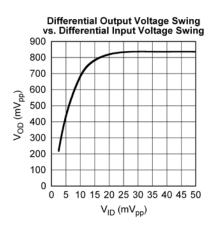












### **Description**

The SY88973BL low-power, limiting post amplifier operates from a single +3.3V ±10% power supply, over an industrial temperature range of  $-40^{\circ}\text{C}$  to +85°C. Signals with data rates up to 3.2Gbps and as small as  $10\text{mV}_{PP}$  can be amplified. Figure 1 shows the allowed input voltage swing. The SY88973BL generates a LOS output, providing feedback to /EN for output stability. LOSLVL sets the sensitivity of the input amplitude detection.

### Input Amplifier/Buffer

The SY88973BL's inputs are internally terminated with  $50\Omega$ -to-REF. Unless unaffected by this internal termination scheme, upstream devices need to be AC-coupled to the SY88973BL's inputs. Figure 2 shows a simplified schematic of the input structure.

The high sensitivity of the input amplifier detects and amplifies signals as small as 10mV<sub>PP</sub>. The input amplifier allows input signals as large as 1800mV<sub>PP</sub>. Input signals are linearly amplified with a typical 38dB differential voltage gain. Since it is a limiting amplifier, the SY88973BL outputs, typically 800mV<sub>PP</sub>, voltage-limited waveforms for input signals that are greater than 10mV<sub>PP</sub>. Applications requiring the SY88973BL to operate with high gain should have the upstream TIA placed as close as possible to the SY88973BL's input pins to ensure the device's best performance.

#### **Output Buffer**

The SY88973BL's CML output buffer is designed to drive  $50\Omega$  lines. The output buffer requires appropriate termination for proper operation. An external  $5\Omega$  resistor - to-VCC or equivalent for each output pin provides this. Figure 3 shows a simplified schematic of the output structure and includes an appropriate termination method. Of course, driving a downstream device with a CML input that is internally terminated with  $5\Omega$  -to-V<sub>CC</sub> eliminates the need for external termination. As noted in the previous section, the amplifier outputs, typically,  $800\text{mV}_{PP}$ , waveforms across  $25\Omega$  total loads. The output buffer, thus, switches typically 16mA tail-current. Figure 4 shows the power supply current measurement which excludes the 16mA tail-current.

### Loss-of-Signal (LOS)

The SY88973BL incorporates a chatter-free, LOS open-collector TTL output. For proper operation, an external  $4.75k\Omega$  to  $10k\Omega$  pull-up resistor between LOS and Vcc is required. LOS is used to determine that the input amplitude is too small to be considered a valid input. LOS asserts high if the input amplitude falls below the threshold set by LOSLVL and de-asserts low otherwise. LOS can be fed back to the enable (/EN) input to maintain output

stability under a loss of signal condition. /EN de-assert low the true output signal without removing the input signals. Typically, 4.6dB LOS hysteresis is provided to prevent chattering.

#### Loss-of-Signal Level Set

A programmable, loss-of-signal level set pin sets the threshold of the input amplitude detection. Connecting an external resistor between  $V_{\rm CC}$  and LOSLVL sets the voltage at LOSLVL. This voltage ranges from  $V_{\rm CC}$  to  $V_{\rm REF}.$  The external resistor creates a voltage divider between  $V_{\rm CC}$  and REF as shown in Figure 6. If desired, an appropriate external voltage may be applied rather than using a resistor. The relationship between  $V_{\rm LOSLVL}$  and  $R_{\rm LOSLVL}$  is given by:

$$V_{LOSLVL} = V_{CC} - 1.3 \frac{R_{LOSLVL}}{R_{LOSLVL} + 2.8}$$

where voltages are in volts and resistances are in  $k\Omega$ .

The smaller the external resistor, which implies a smaller voltage difference from  $L_{\text{OSLVL}}$  to  $V_{\text{CC}},$  the lower the LOS sensitivity. Hence, larger input amplitude is required to deassert LOS. The "Typical Operating Characteristics" section contains graphs showing the relationship between the input amplitude detection sensitivity and  $V_{\text{LOSLVL}}$  or  $R_{\text{LOSLVL}}.$ 

### **Hysteresis**

The SY88973BL provides typically 4.6dB LOS electrical hysteresis. By definition, a power ratio measured in dB is 10log (power ratio). Power is calculated as V2<sub>IN</sub>/R for an electrical signal. Hence, the same ratio can be stated as 20log (voltage ratio). While in linear mode, the electrical voltage input changes linearly with the optical power and the ratios change linearly as well. Therefore, the optical hysteresis in dB is half the electrical hysteresis in dB given in the datasheet. The SY88973BL provides typically 2.3dB LOS optical hysteresis. As the SY88973BL is an electrical device, this datasheet refers to hysteresis in electrical terms. With 4.6dB LOS hysteresis, a voltage factor of 1.7 is required to de-assert LOS.

### **Hysteresis and Sensitivity Improvement**

If increased LOS sensitivity and hysteresis are required, an application note entitled "Notes on Sensitivity and Hysteresis in Micrel Post Amplifiers" is available at: <a href="http://www.micrel.com/">http://www.micrel.com/</a> PDF/HBW/App-Notes/an-45.pdf.

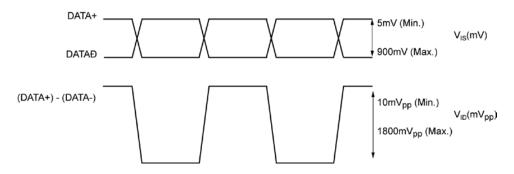


Figure 1. VIS and VID Definition

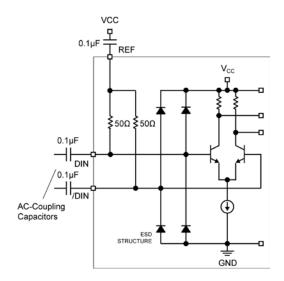
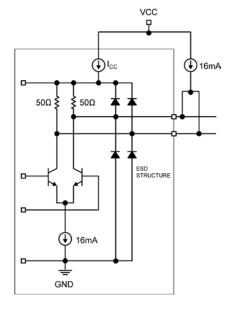


Figure 2. Input Structure



**Figure 4. Power Supply Current Measurement** 

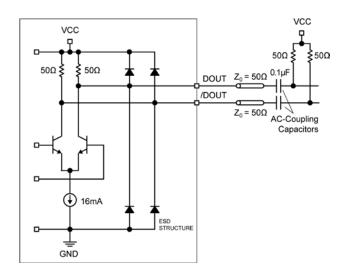


Figure 3. Output Structure

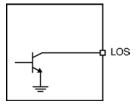


Figure 5. LOS Output Structure

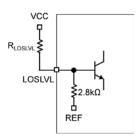
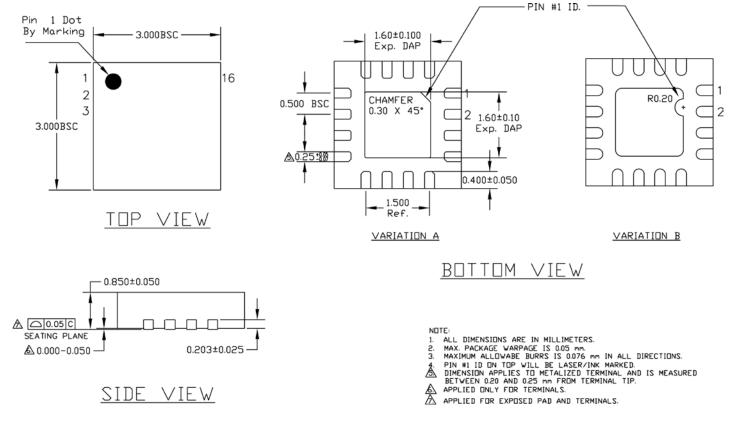
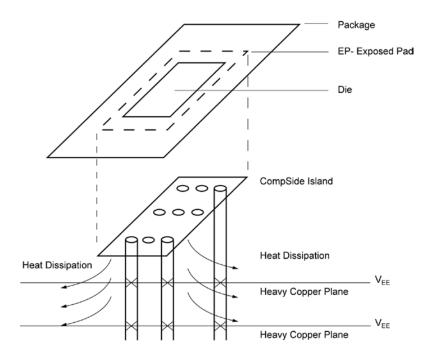


Figure 6. LOSLVL Setting Circuit

### **Package Information**



16-Pin QFN



PCB Thermal Consideration for 16-Pin QFN Package (Always solder, or equivalent, the exposed pad to the PCB)

### **Package Notes:**

- 1. Package meets Level 2 qualification.
- 2. All parts are dry-packaged before shipment.
- 3. Exposed pad must be soldered to a ground for proper thermal management; solder void has to be less than 50% of the epad area.

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